



Rectifier Diode

Replaces January 2000 version, DS4179-5.0

DS4179-6.0 August 2001

APPLICATIONS

- Rectification
- Freewheel Diode
- DC Motor Control
- Power Supplies
- Welding
- Battery Chargers

FEATURES

- Double Side Cooling
- High Surge Capability

VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage V _{RRM} V	Conditions
DNB63 15	1500	$V_{RSM} = V_{RRM} + 100V$
DNB63 14	1400	now nnw
DNB63 13	1300	
DNB63 12	1200	
DNB63 11	1100	

Lower voltage grades available.

KEY PARAMETERS

V_{RRM} 1500V I_{F(AV)} 5794A I_{FSM} 57000A

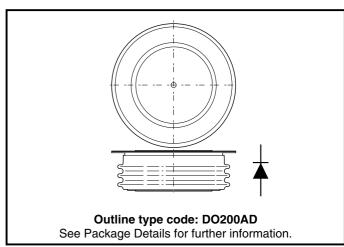


Fig. 1 Package outline



CURRENT RATINGS

T_{case} = 75°C unless otherwise stated

Symbol	Parameter	Conditions	Max.	Units			
Double Sid	Double Side Cooled						
I _{F(AV)}	Mean forward current	Half wave resistive load	5794	Α			
I _{F(RMS)}	RMS value	-	9101	Α			
I _F	Continuous (direct) forward current	-	7934	Α			
Single Side Cooled (Anode side)							
I _{F(AV)}	Mean forward current	Half wave resistive load	4230	Α			
I _{F(RMS)}	RMS value	-	6645	Α			
I _F	Continuous (direct) forward current	-	5468	Α			

$T_{case} = 100$ °C unless otherwise stated

Symbol	Parameter	Conditions	Max.	Units			
Double Sic	Double Side Cooled						
I _{F(AV)}	Mean forward current	Half wave resistive load, T _{case} = 100°C	4850	А			
I _{F(RMS)}	RMS value	$T_{\text{case}} = 100^{\circ}\text{C}$	7615	Α			
l _F	Continuous (direct) forward current	$T_{\rm case} = 100^{\circ} C$	6600	Α			
Single Side Cooled (Anode side)							
I _{F(AV)}	Mean forward current	Half wave resistive load, T _{case} = 100°C	3540	Α			
I _{F(RMS)}	RMS value	$T_{\text{case}} = 100^{\circ}\text{C}$	5560	Α			
l _F	Continuous (direct) forward current	T _{case} = 100°C	4500	Α			



SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) forward current	10ms half sine; T _{case} = 190°C	52.0	kA
l ² t	I ² t for fusing	$V_R = 50\% V_{RRM} - 1/4 sine$	13.5 x 10 ⁶	A²s
I _{FSM}	Surge (non-repetitive) forward current	10ms half sine; T _{case} = 190°C	57.0	kA
l²t	I ² t for fusing	V _R = 0	16.2 x 10 ⁶	A²s

THERMAL AND MECHANICAL DATA

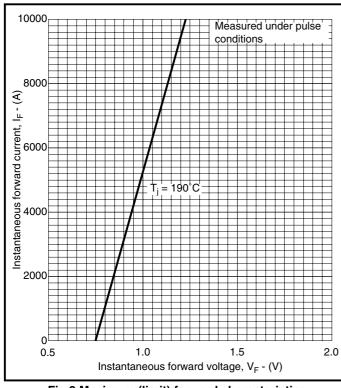
Symbol	Parameter	Conditions		Min.	Max.	Units
	Thermal resistance - junction to case	Double side cooled	dc	-	0.013	°C/W
$R_{th(j-c)}$		Single side cooled	Anode dc	-	0.021	°C/W
			Cathode dc	-	0.034	°C/W
Б	Thermal resistance - case to heatsink	Clamping force 45.0kN with mounting compound	Double side	-	0.003	°C/W
$R_{th(c-h)}$			Single side	-	0.006	°C/W
$T_{v_{j}}$	Virtual junction temperature	Forward (conducting)		-	200	°C
		Reverse (blocking)		-	190	°C
T _{stg}	Storage temperature range			-55	190	°C
-	Clamping force			40.0	48.0	kN



CHARACTERISTICS

Symbol	Parameter	Conditions	Min.	Max.	Units
V _{FM}	Forward voltage	At 3000A peak, T _{case} = 25°C	-	1.05	V
I _{RRM}	Peak reverse current	At V _{RRM} , T _{case} = 190°C	-	60	mA
Q_s	Total stored charge	$I_F = 1000A$, $dI_{RR}/dt = 50A/\mu s$ $-T_{case} = 175^{\circ}C$, $V_R = 100V$	-	4000	μC
I _{RM}	Peak recovery current		-	600	Α
t _{rr}	Reverse recovery time		-	20	μs
V _{TO}	Threshold voltage	At T _{vj} = 190°C	-	0.75	V
r _T	Slope resistance	At T _{vj} = 190°C	-	0.046	mΩ

CURVES



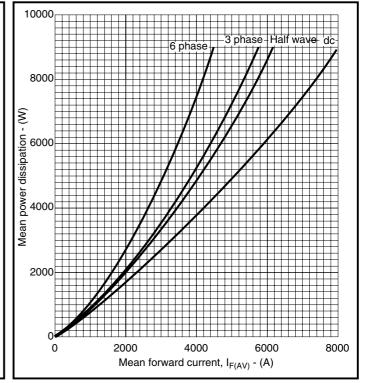


Fig.2 Maximum (limit) forward characteristics

V_{FM} Equation:-

$$V_{FM} = A + BIn (I_F) + C.I_F + D.\sqrt{I_F}$$

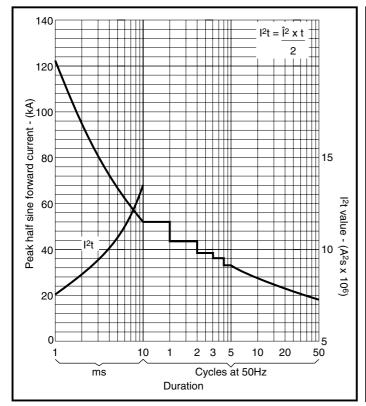
Fig.3 Dissipation curves

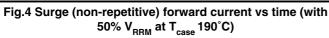
Where A = 0.517184B = 0.035583

 $C = 4.94 \times 10^{-5}$ D = -0.0011

these values are valid for $T_i = 125^{\circ}C$ for $I_F 500A$ to 10000A







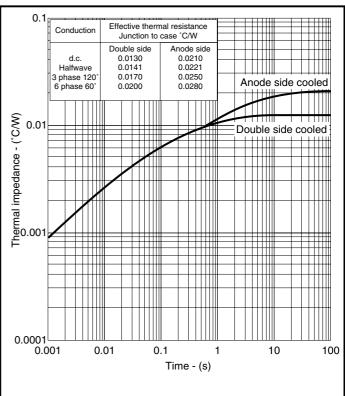
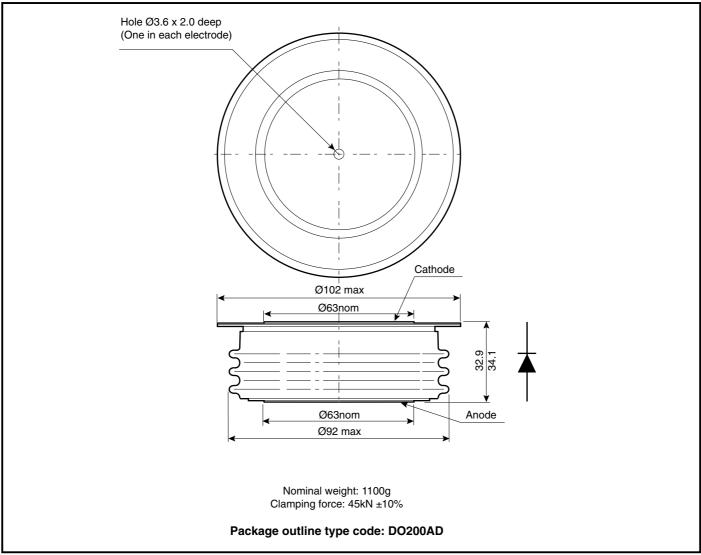


Fig.5 Maximum (limit) transient thermal impedance - junction to case



PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



Note:

1. Package maybe supplied with pins and/or tags.

POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.

Stresses above those listed in this data sheet may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed.



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